

# NIKO-SEM P-Channel Logic Level Enhancement Mode P1403EVG

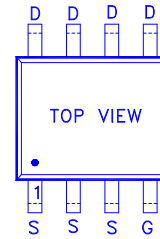
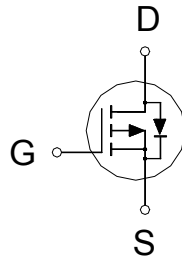
## Field Effect Transistor

SOP-8  
Halogen-Free & Lead-Free



### PRODUCT SUMMARY

$V_{(BR)DSS}$	$R_{DS(ON)}$	$I_D$
-30	14m $\Omega$	-11



4 :GATE  
5,6,7,8 :DRAIN  
1,2,3 :SOURCE

**100% UIS tested**

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25\text{ }^\circ\text{C}$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS	SYMBOL	LIMITS	UNITS
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 25$	V
Continuous Drain Current	$I_D$	$T_A = 25\text{ }^\circ\text{C}$	-11
		$T_A = 70\text{ }^\circ\text{C}$	-9
Pulsed Drain Current <sup>1</sup>	$I_{DM}$	-50	A
Avalanche Current	$I_{AS}$	-43	
Avalanche Energy	$E_{AS}$	90	mJ
Power Dissipation	$P_D$	$T_A = 25\text{ }^\circ\text{C}$	2.5
		$T_A = 70\text{ }^\circ\text{C}$	1.6
Operating Junction & Storage Temperature Range	$T_j, T_{stg}$	-55 to 150	$^\circ\text{C}$

### THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Case	$R_{\theta JC}$		25	$^\circ\text{C} / \text{W}$
Junction-to-Ambient	$R_{\theta JA}$		50	$^\circ\text{C} / \text{W}$

<sup>1</sup>Pulse width limited by maximum junction temperature.

### ELECTRICAL CHARACTERISTICS ( $T_A = 25\text{ }^\circ\text{C}$ , Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$	-30			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$	-1	-1.7	-3	V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{V}, V_{GS} = \pm 25\text{V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -24\text{V}, V_{GS} = 0\text{V}$			-1	$\mu\text{A}$
		$V_{DS} = -20\text{V}, V_{GS} = 0\text{V}, T_J = 125\text{ }^\circ\text{C}$			-10	

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Drain-Source On-State Resistance <sup>1</sup>	$R_{DS(ON)}$	$V_{GS} = -4.5V, I_D = -9A$	14	22	m $\Omega$
		$V_{GS} = -10V, I_D = -12A$	9	14	
Forward Transconductance <sup>1</sup>	$g_{fs}$	$V_{DS} = -10V, I_D = -12A$	28		S
<b>DYNAMIC</b>					
Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = -15V, f = 1MHz$	2510		pF
Output Capacitance	$C_{oss}$		449		
Reverse Transfer Capacitance	$C_{rss}$		349		
Gate Resistance	$R_g$	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$	7.3		$\Omega$
Total Gate Charge <sup>2</sup>	$Q_{g(VGS=10V)}$	$V_{DS} = 0.5V_{(BR)DSS}, V_{GS} = -10V, I_D = -12A$	48		nC
	$Q_{g(VGS=4.5V)}$		26		
Gate-Source Charge <sup>2</sup>	$Q_{gs}$		7		
Gate-Drain Charge <sup>2</sup>	$Q_{gd}$		9		
Turn-On Delay Time <sup>2</sup>	$t_{d(on)}$		12		
Rise Time <sup>2</sup>	$t_r$	16			
Turn-Off Delay Time <sup>2</sup>	$t_{d(off)}$	50			
Fall Time <sup>2</sup>	$t_f$	100			
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (<math>T_A = 25^\circ C</math>)</b>					
Continuous Current	$I_S$			-2.1	A
Forward Voltage <sup>1</sup>	$V_{SD}$	$I_F = I_S, V_{GS} = 0V$		-1.2	V

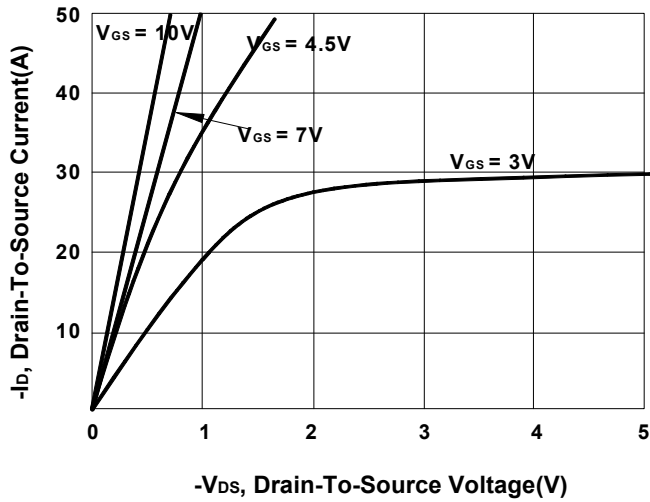
<sup>1</sup>Pulse test : Pulse Width  $\leq 300 \mu sec$ , Duty Cycle  $\leq 2\%$ .

<sup>2</sup>Independent of operating temperature.

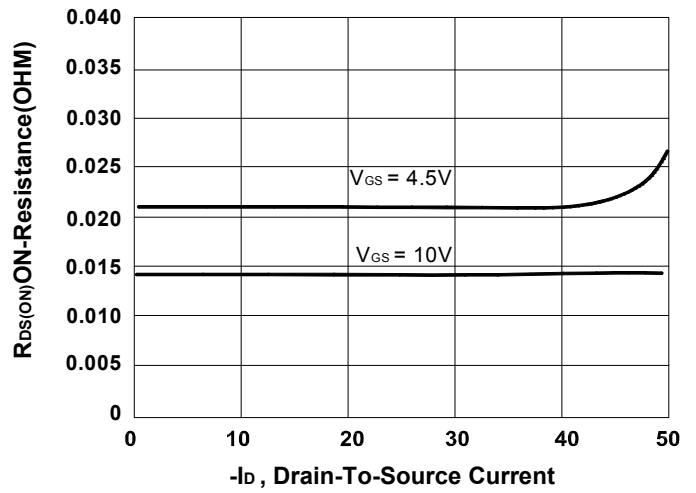
**REMARK: THE PRODUCT MARKED WITH "P1403EVG", DATE CODE or LOT #**

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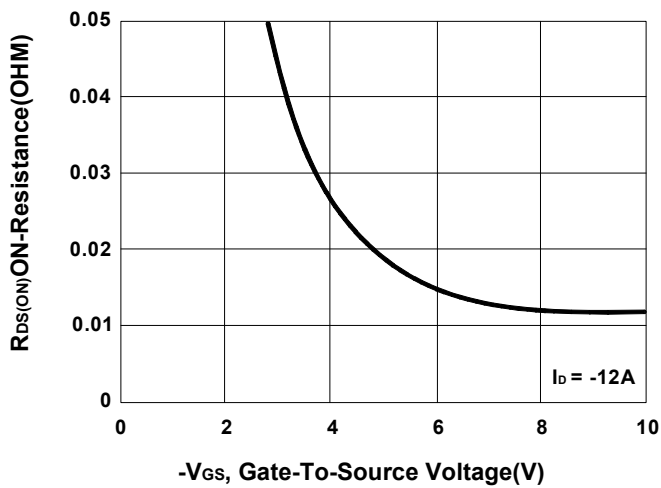
**Output Characteristics**



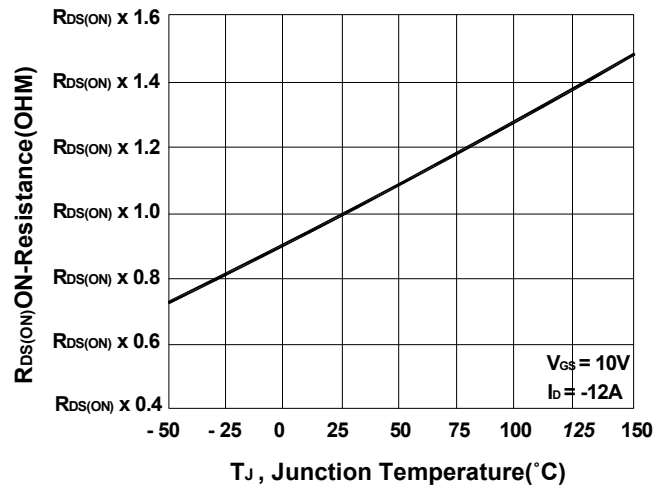
**On-Resistance VS Drain Current**



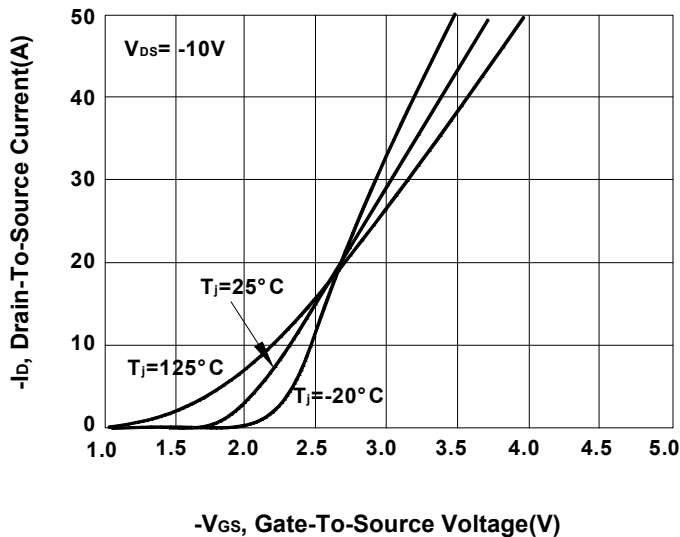
**On-Resistance VS Gate-To-Source**



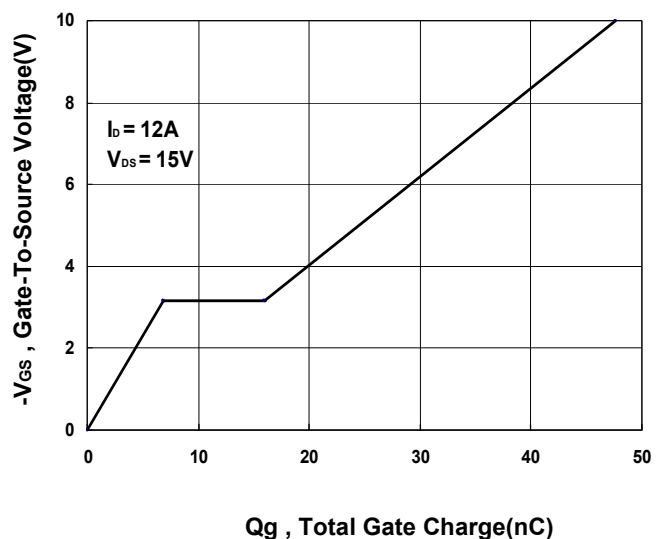
**On-Resistance VS Temperature**



**Transfer Characteristics**

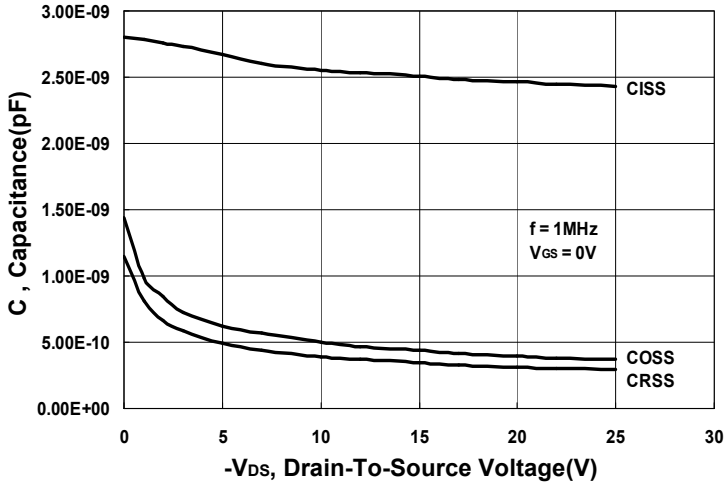


**Gate charge Characteristics**

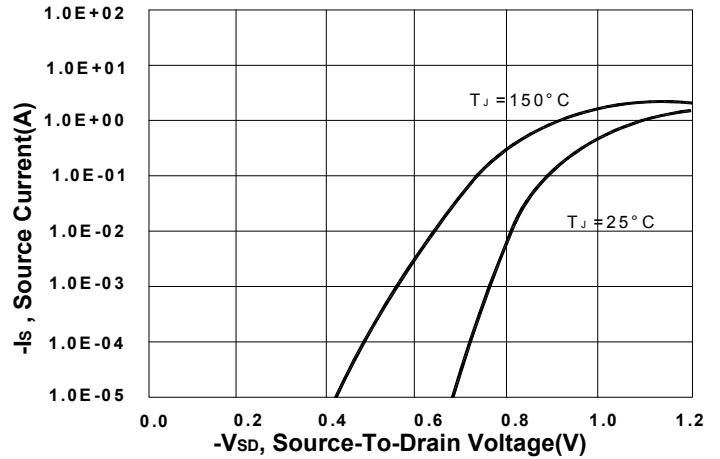


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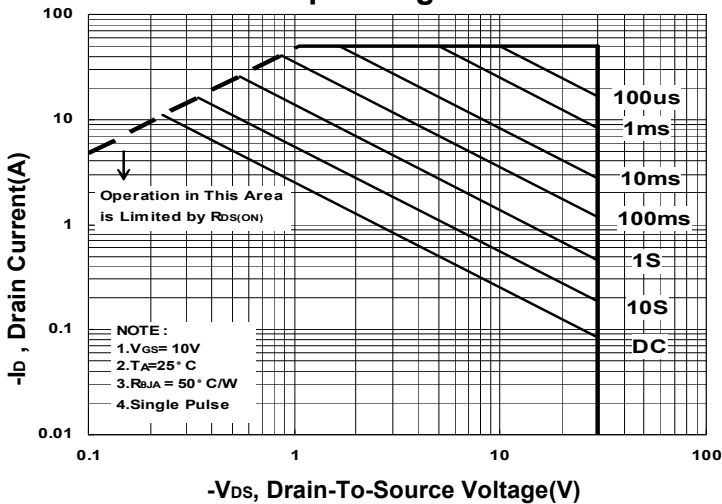
**Capacitance Characteristic**



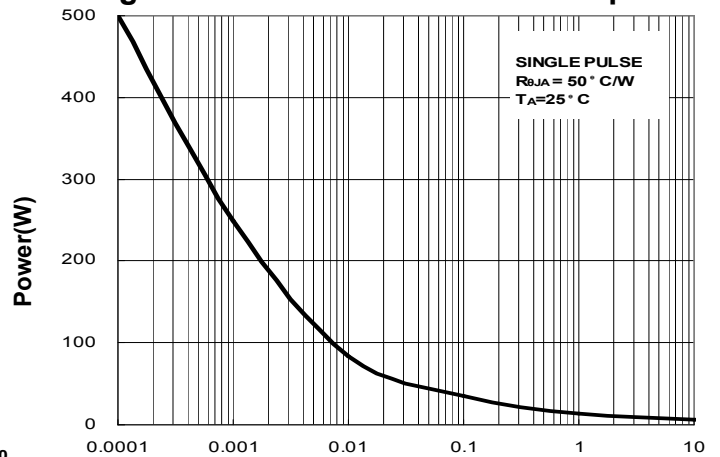
**Body Diode Forward Voltage VS Source current**



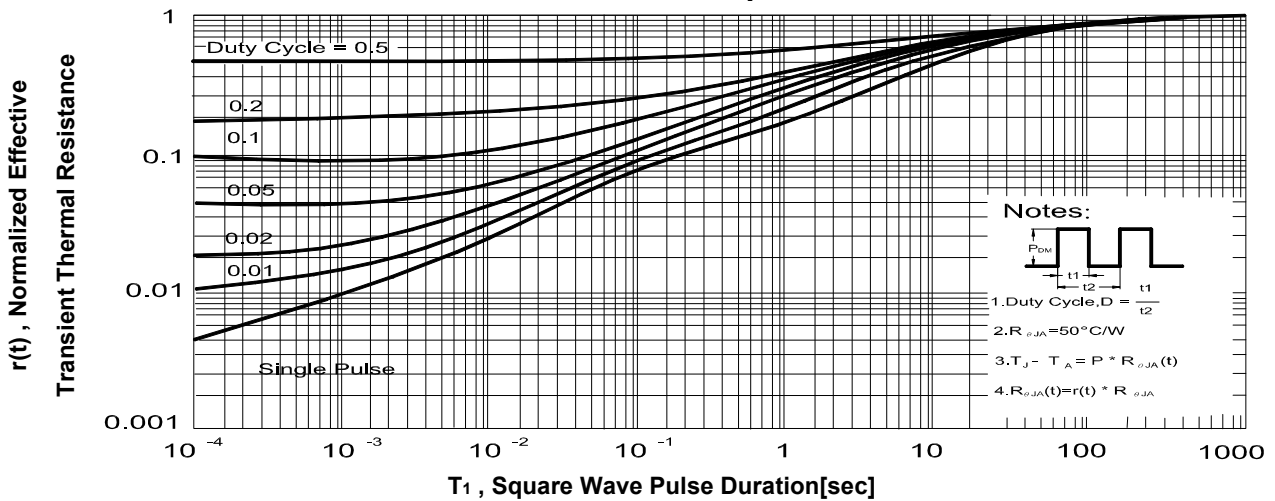
**Safe Operating Area**



**Single Pulse Maximum Power Dissipation**



**Transient Thermal Response Curve**



**SOP-8 MECHANICAL DATA**

Dimension	mm			Dimension	mm		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.70	4.90	5.10	H	0.40	0.715	0.83
B	3.70	3.90	4.10	I	0.19	0.22	0.26
C	5.80	6.00	6.20	J	0.25	0.375	0.5
D	0.33	0.445	0.51	K	0°	4°	8°
E		1.27		L			
F	1.20	1.375	1.62	M			
G	0.08	0.175	0.28	N			

